

# HMC349LP4C

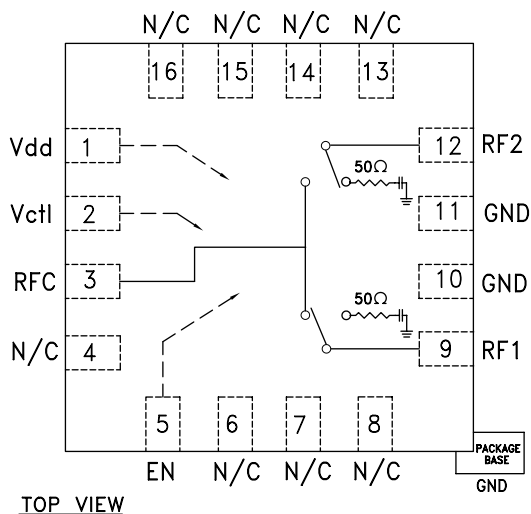
## HIGH ISOLATION SPDT NON-REFLECTIVE SWITCH, DC - 4.0 GHz

### Typical Applications

The HMC349LP4C is ideal for:

- Basestation Infrastructure
- MMDS & 3.5 GHz WLL
- CATV/CMTS
- Test Instrumentation

### Functional Diagram



### Features

High Isolation: 67 dB @ 1 GHz  
62 dB @ 2 GHz

Single Positive Control: 0/+5V

+52 dBm Input IP3

Non-Reflective Design

All Off State

16 mm<sup>2</sup> Leadless QFN SMT Package

### General Description

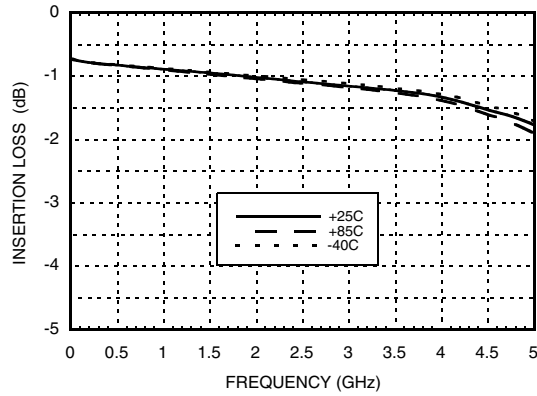
The HMC349LP4C is a high isolation non-reflective DC to 4 GHz GaAs MESFET SPDT switch in a low cost leadless surface mount package. The switch is ideal for cellular/PCS/3G basestation applications yielding 60 to 65 dB isolation, low 0.9 dB insertion loss and +52 dBm input IP3. Power handling is excellent up through the 3.5 GHz WLL band with the switch offering a P1dB compression point of +31 dBm. On-chip circuitry allows a single positive voltage control of 0/+5 Volts at very low DC currents. An enable input (EN) set to logic high will put the switch in an "all off" state.

### Electrical Specifications, $T_A = +25^\circ\text{C}$ , $V_{ctl} = 0/+5\text{ Vdc}$ , $V_{dd} = +5\text{ Vdc}$ , 50 Ohm System

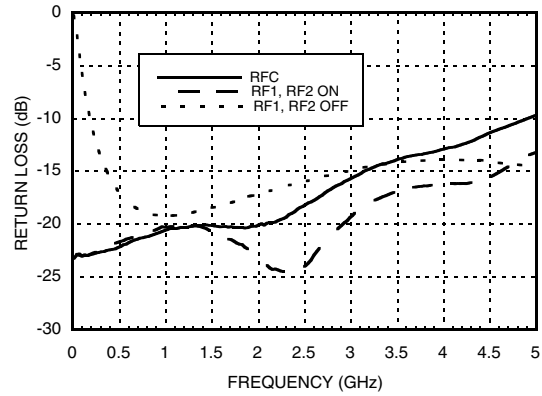
Parameter	Frequency	Min.	Typ.	Max.	Units
Insertion Loss	DC - 1.0 GHz		0.9	1.2	dB
	DC - 2.0 GHz		1.0	1.3	dB
	DC - 3.0 GHz		1.2	1.5	dB
	DC - 4.0 GHz		1.4	1.7	dB
Isolation (RFC to RF1/RF2)	DC - 1.0 GHz	60	67		dB
	DC - 4.0 GHz	55	62		dB
Return Loss (On State)	DC - 2.0 GHz		20		dB
	DC - 3.0 GHz		15		dB
	DC - 4.0 GHz		13		dB
Return Loss (Off State)	0.5 - 4.0 GHz		15		dB
Input Power for 1 dB Compression	0.25 - 4.0 GHz	27	31		dBm
Input Third Order Intercept (Two-Tone Input Power = +7 dBm Each Tone)	0.25 - 1.0 GHz		52		dBm
	1.0 - 2.0 GHz		50		dBm
	2.0 - 3.0 GHz		49		dBm
	3.0 - 4.0 GHz		46		dBm
Switching Speed	DC - 4.0 GHz				
			50		ns
			120		ns

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**Insertion Loss**

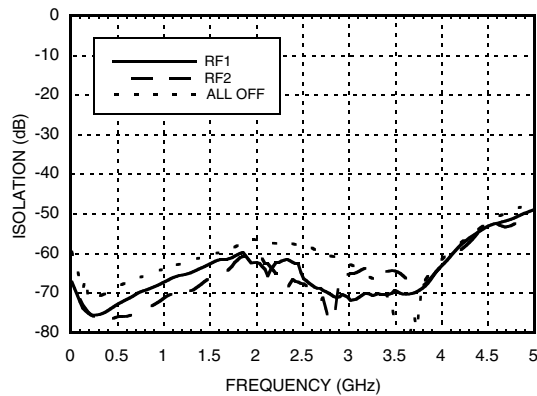


**Return Loss**

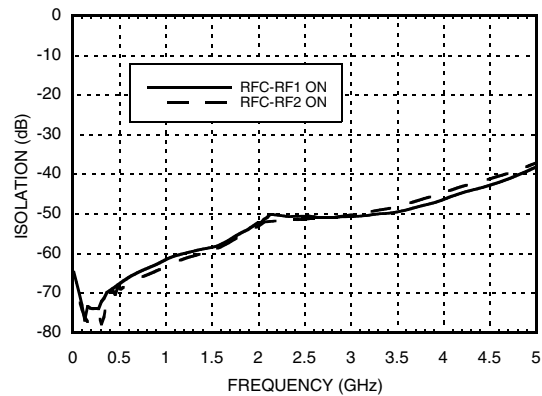


Note: RFC is reflective in "all off" state.

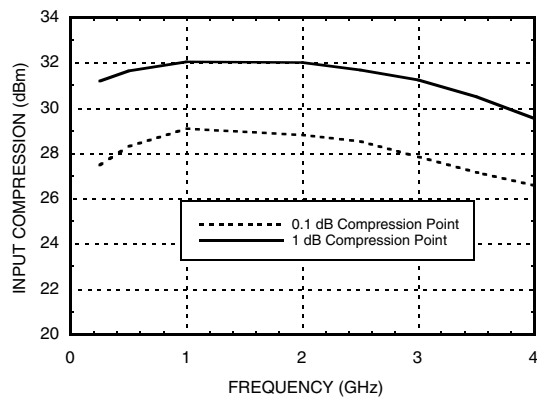
**Isolation Between  
Ports RFC and RF1 / RF2**



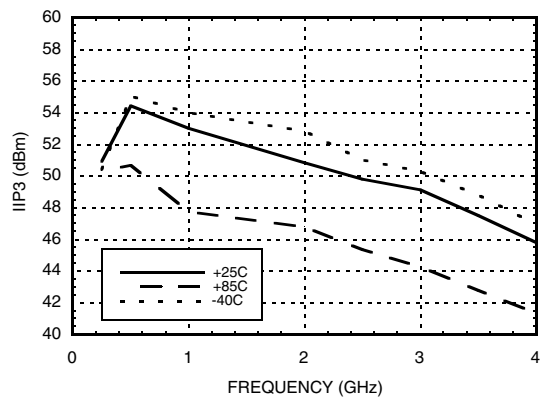
**Isolation Between Ports RF1 and RF2**



**0.1 and 1 dB Input Compression Point**



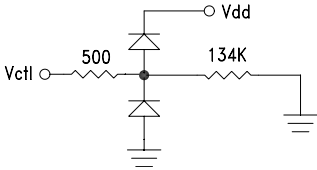
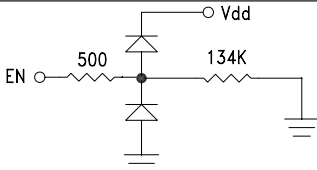

**Input Third Order Intercept Point**





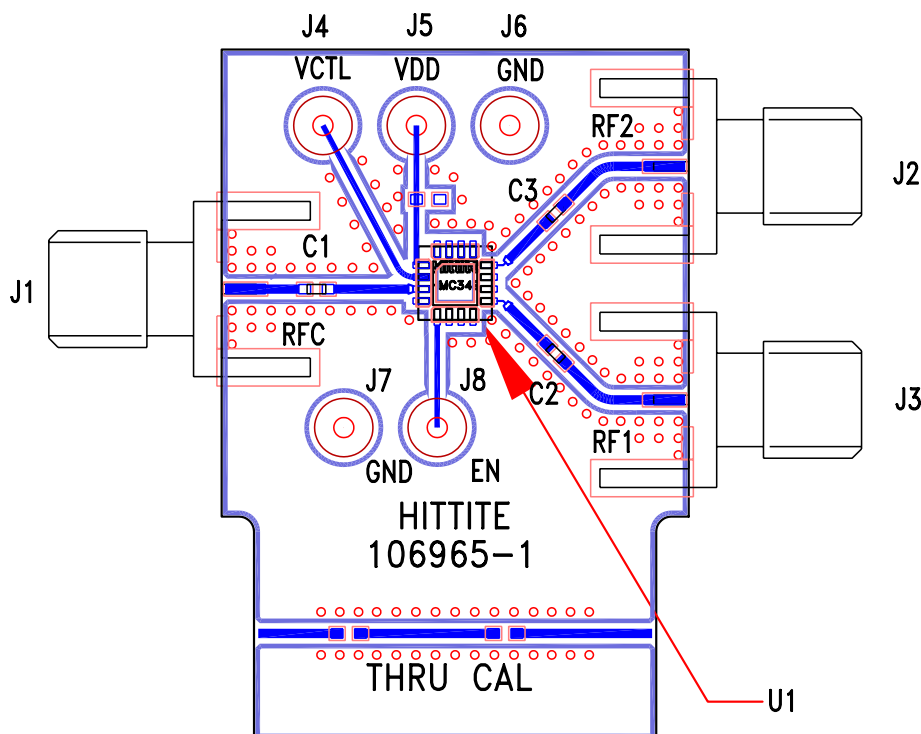
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### Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	Vdd	Supply Voltage.	
2	Vctl	Control input. See truth and control voltage tables.	
3, 9, 12	RFC, RF1, RF2	These pins are DC coupled and matched to 50 Ohms. Blocking capacitors are required.	
4, 6, 7, 8, 13, 14, 15, 16	N/C	No connection. These pins may be connected to RF ground. Performance will not be affected.	
5	EN	Enable. See truth and control voltage tables.	
10, 11	GND	Package bottom must also be connected to PCB RF ground.	

# HIGH ISOLATION SPDT NON-REFLECTIVE SWITCH, DC - 4.0 GHz

## Evaluation PCB



## List of Material for Evaluation PCB 106975\*

Item	Description
J1 - J3	PC Mount SMA RF Connector
J4 - J8	DC Pin
C1 - C3	100 pF Capacitor, 0402 Pkg.
U1	HMC349LP4C SPDT Switch
PCB**	106965 Evaluation PCB

\*\* Circuit Board Material: Rogers 4350

\* Reference this number when ordering complete evaluation PCB.

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads and backside ground slug should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

***HIGH ISOLATION SPDT  
NON-REFLECTIVE SWITCH, DC - 4.0 GHz***

***Notes:***